SILICON NPN TRIPLE DIFFUSED MESA TYPE
(DARLINGTON POWER)

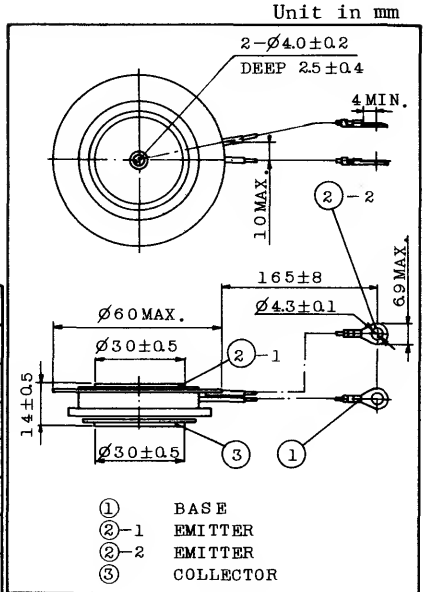
2SD1165A

INDUSTRIAL APPLICATIONS

HIGH POWER SWITCHING APPLICATION.
DC-AC POWER INVERTER APPLICATION.
MOTOR CONTROL APPLICATION.

FEATURES:
. High Voltage : $V_{CEO(SUS)}$ >900V
. Triple Diffused Design
. Darlington Design

Unit in mm



JEDEC	—
EIAJ	—
TOSHIBA	2-60B1A

Weight : 150g

MAXIMUM RATINGS (Ta=25°C)

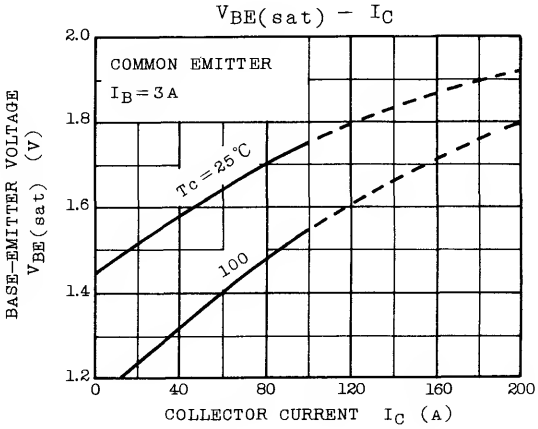
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	1000	V
Collector-Emitter Voltage	$V_{CEO(SUS)}$	900	V
Emitter-Base Voltage	V_{EBO}	6	V
Collector Current	I_C	100	A
Emitter Current	I_E	-100	A
Base Current	I_B	12	A
Thermal Resistance (Double Side Cooling)	$R_{th(j-c)}$	0.08	°C/W
Junction Temperature	T_j	125	°C
Storage Temperature	T_{stg}	-40~150	°C
Mounting Force Required	F	500±50	kg

ELECTRICAL CHARACTERISTICS (Ta=25°C)

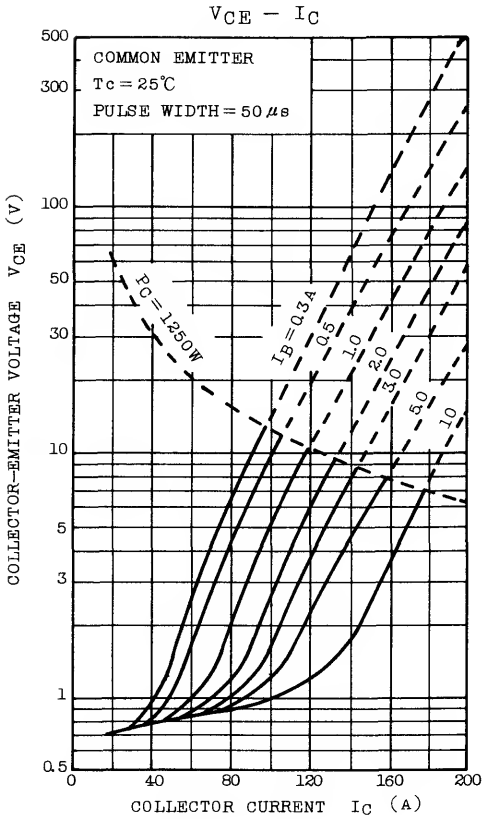
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Current Transfer Ratio		h_{FE}	V_{CE}=5V, I_C=100A	60	-	-	
			V_{CE}=5V, I_C=50A	-	500	-	
Collector-Emitter Sustaining Voltage		$V_{CEO(SUS)}$	I_C=0.5A, L=40mH	900	-	-	V
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	I_C=100A, I_B=3A (Note)	-	-	2.0	V
Base-Emitter Saturation Voltage		$V_{BE(sat)}$		-	-	2.5	V
Collector Cut-off Current		I_{CBO}	V_{CB}=1000V, I_E=0	-	-	2	mA
Emitter Cut-off Current		I_{EBO}	V_{EB}=6V, I_C=0	-	-	1000	mA
Switching Time	Turn-on Time	t_{on}	I_C=100A, I_{B1}=3A,	-	1.0	2.0	μs
	Storage Time	t_{stg}	$-I_{B2}$=6A, V_C=600V,	-	20	25	μs
	Fall Time	t_f	R_L=6Ω	-	3.0	5.0	μs

Note : Pulse Test: Pulse Width ≦300μs Duty Cycle ≦3%
Mounting Force; F=500kg

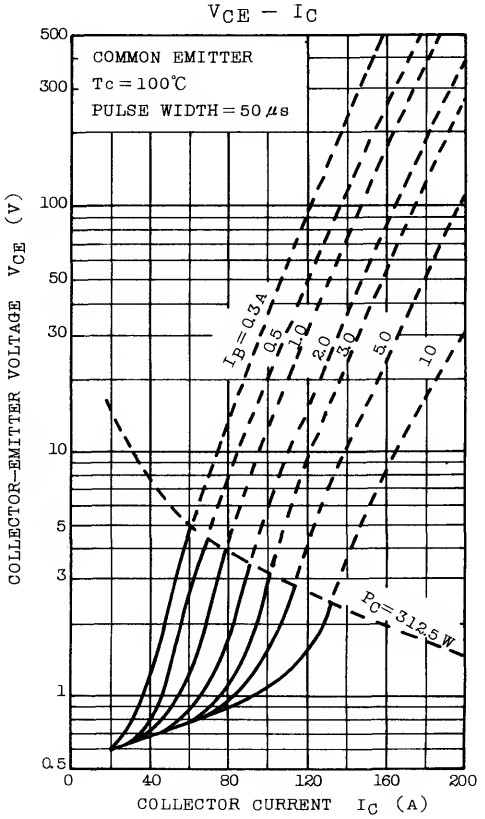
$V_{BE(sat)} - I_C$



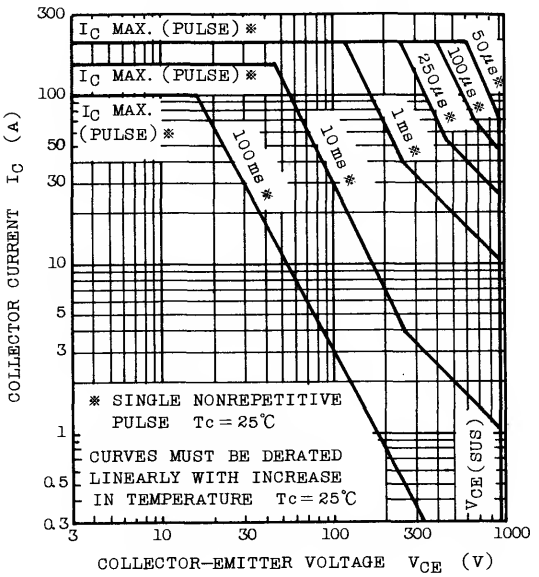
$V_{CE} - I_C$



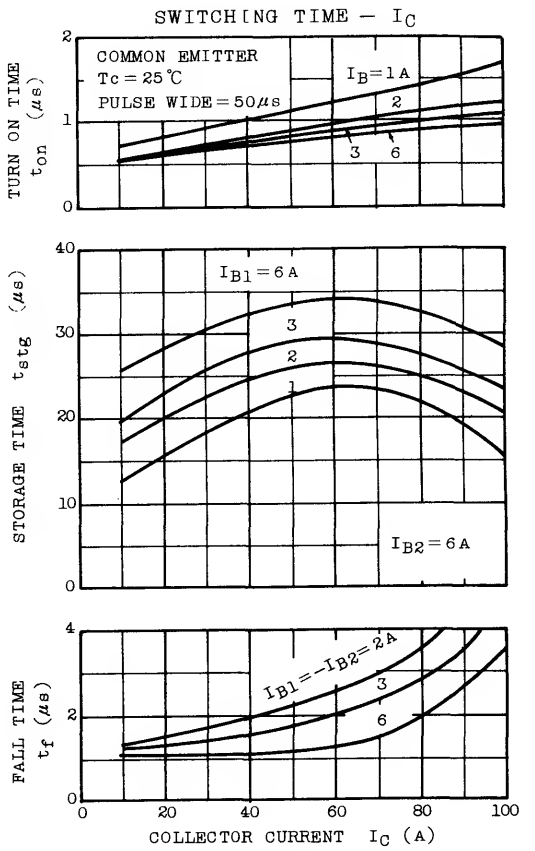
$V_{CE} - I_C$



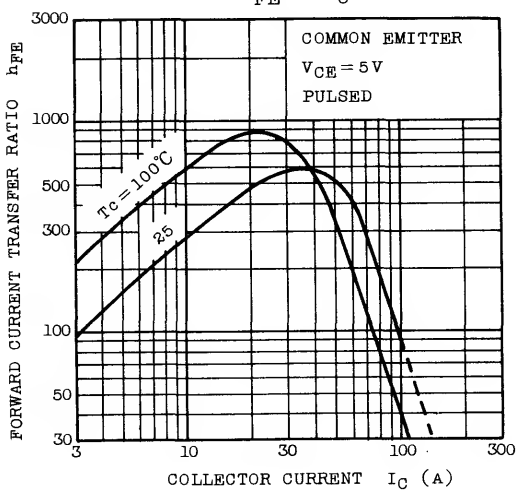
SAFE OPERATING AREA



SWITCHING TIME — I_C



h_{FE} — I_C



TRANSIENT THERMAL IMPEDANCE (JUNCTION TO CASE)